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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Bryant ct al.

Examiner: Gebremariam, Samuel A.

Scrial No.: 09/683,486

Art Unit: 2811

Filed: 1/7/2002

For: FIN-BASED DOUBLE POLY DYNAMIC THRESHOLD CMOS FET WITH SPACER GATE AND METHOD OF FABRICATION

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

above-identified application as follows:

**AMENDMENT** 

In response to the Final Office Action mailed September 10, 2003, please amend the

Sir:

09/683,486